## Nch 100V 80A Power MOSFET

V <sub>DSS</sub>	100V
R <sub>DS(on)</sub> (Max.)	6.2mΩ
I <sub>D</sub>	±80A
P <sub>D</sub>	142W

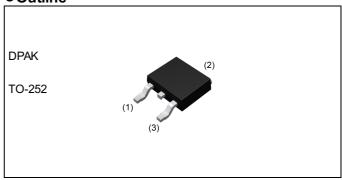
# ● Features

Low on-resistance Pb-free plating;RoHS compliant 100% Avalanche tested AEC-Q101 qualified

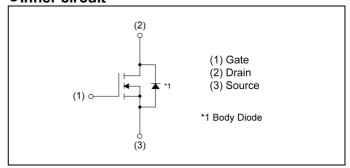
## Application

**Automotive Systems** 

### Outline



## •Inner circuit



Packaging specifications

<b>●</b> Packa	Jing specifications	Prackaging specifications						
	Packing	Embossed Tape						
	Reel size (mm)	330						
Type	Tape width (mm)	16						
	Quantity (pcs)	2500						
	Taping code	TL						
	Marking	AG194FPD3						

## ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		$V_{DSS}$	100	V
Continuous drain current	V <sub>GS</sub> = 10V	I <sub>D</sub> *1	±80	Α
Pulsed drain current	I <sub>DP</sub> *2	±160	Α	
Gate - Source voltage		V <sub>GSS</sub>	±20	V
Avalanche current, single pulse	I <sub>AS</sub> *3	37	Α	
Avalanche energy, single pulse	E <sub>AS</sub> *3	55	mJ	
Power dissipation	P <sub>D</sub> *1	142	W	
Junction temperature	T <sub>j</sub>	175	°C	
Operating junction and storage te	mperature range	T <sub>stg</sub>	-55 to +175	°C

## ●Thermal resistance

Parameter	Symbol	Values			Linit
		Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *1	-	-	1.05	°C/W

## ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatav	Symbol Conditions —		Values			Unit
Parameter			Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j} I_D = 1 \text{mA}$ referenced to 25°C		55	-	mV/°C
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V	-	-	1	μА
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±500	nA
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 9.2$ mA	2.0	-	4.0	V
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 9.2mA referenced to 25°C	-	-5.9	-	mV/°C
Static drain - source	D *4	V <sub>GS</sub> = 10V, I <sub>D</sub> = 80A	-	4.8	6.2	mO.
on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 6V, I <sub>D</sub> = 40A	-	5.9	8.2	mΩ
Gate resistance	$R_G$	f = 1MHz, open drain	-	2.0	-	Ω
Forward Transfer Admittance	Y <sub>fs</sub>  *4	V <sub>DS</sub> = 5V, I <sub>D</sub> = 10A	17	-	-	S

<sup>\*1</sup>  $T_c$ =25°C , Limited only by maximum junction temperature Tj=175°C.

<sup>\*2</sup> Pw ≤10µs , Duty cycle ≤1%

<sup>\*3</sup> L=0.05mH,  $V_{DD}$ =50V,  $R_G$ =25 $\Omega$ , Starting Tj=25 $^{\circ}$ C, See Fig.3-1,3-2

<sup>\*4</sup> Pulsed

# • Electrical characteristics $(T_a = 25^{\circ}C)$

Dorameter	Cumb of	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	3520	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 50V	-	680	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	1	27	1	
Turn - on delay time	t <sub>d(on)</sub> *4	$V_{DD} \simeq 50V, V_{GS} = 10V$	1	37	1	
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 10A	1	28	1	no
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L \simeq 5\Omega$	-	82	-	ns
Fall time	t <sub>f</sub> *4	$R_G = 1\Omega$	-	23	-	

## • Gate charge characteristics $(T_a = 25^{\circ}C)$

Darameter	Cymahal	Conditions		Values			l limit
Parameter	Symbol			Min.	Тур.	Max.	Unit
Total gate charge	O *4		V <sub>GS</sub> = 10V	-	55.0	-	
Total gate charge	Q <sub>g</sub> *4	V <sub>DD</sub> ≈ 50V		-	29.0	-	<b>"</b> C
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 10A	V <sub>GS</sub> = 6V	-	12.4	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4			-	14.4	-	

## ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Darameter	Cumbal	Conditions	Values			Unit
raiametei	Parameter Symbol Conditions		Min.	Тур.	Max.	Offic
Continuous forward current	I <sub>S</sub> *1	T = 25°C	-	-	80	Α
Pulse forward current	I <sub>SP</sub> *2	T <sub>a</sub> = 25°C	-	-	160	Α
Forward voltage	V <sub>SD</sub> *4	$V_{GS} = 0V, I_{S} = 80A$	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *4	I <sub>S</sub> = 10A, V <sub>GS</sub> =0V	-	71	-	ns
Reverse recovery charge	Q <sub>rr</sub> *4	di/dt = 100A/μs	-	140	-	nC

### • Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

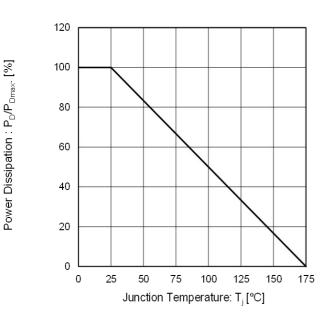
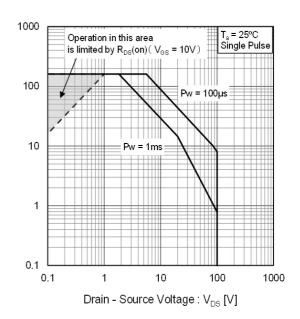


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

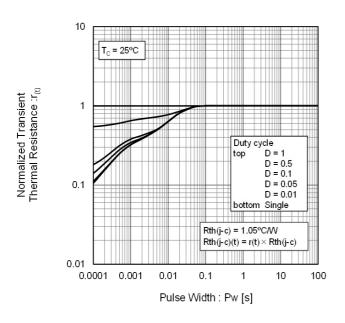
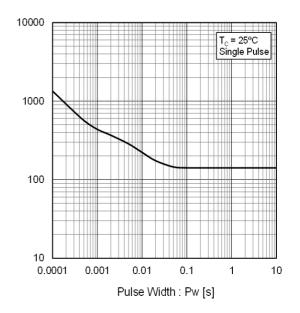


Fig.4 Single Pulse Maximum Power dissipation

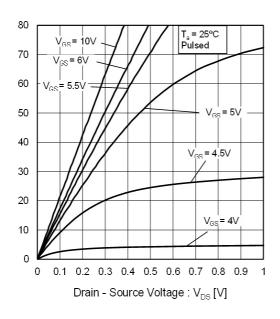


Peak Transient Power: P[W]

Drain Current : I<sub>D</sub> [A]

### • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



Drain Current : I<sub>D</sub> [A]

Fig.6 Typical Output Characteristics(II)

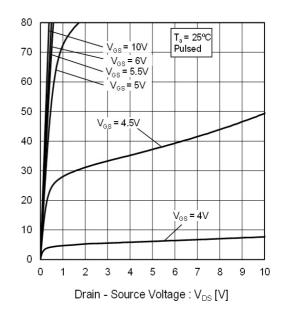
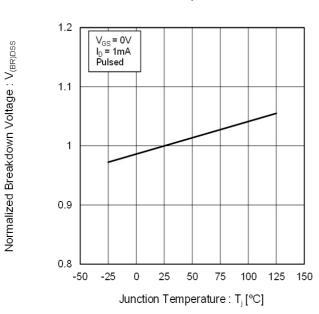


Fig.7 Breakdown Voltage vs.
Junction Temperature



Drain Current: I<sub>D</sub> [A]

## • Electrical characteristic curves

Fig.8 Typical Transfer Characteristics

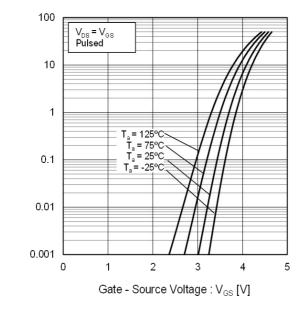


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

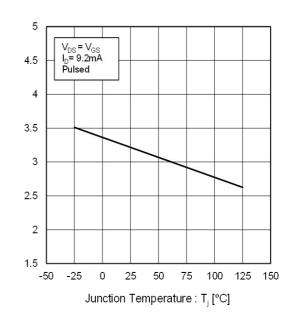
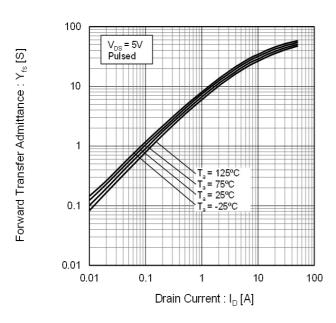


Fig.10 Forward Transfer Admittance vs.
Drain Current



Gate Threshold Voltage : V<sub>GS(th)</sub> [V]

Drain Current Dissipation : I<sub>D</sub>/I<sub>D</sub>max. [%]

### • Electrical characteristic curves

Fig.11 Drain Current Derating Curve

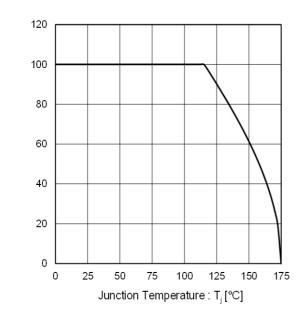
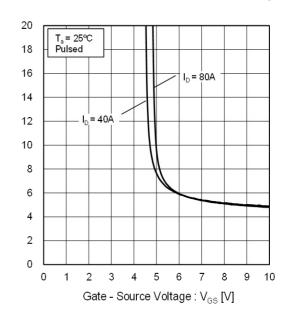
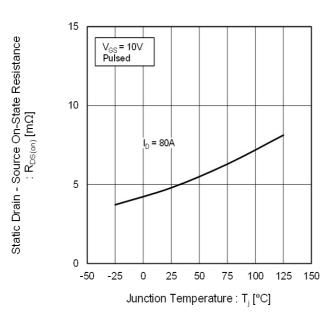


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Static Drain - Source On-State Resistance :  $R_{\mathrm{DS(on)}}\left[m\Omega\right]$ 

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature



### • Electrical characteristic curves

Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)

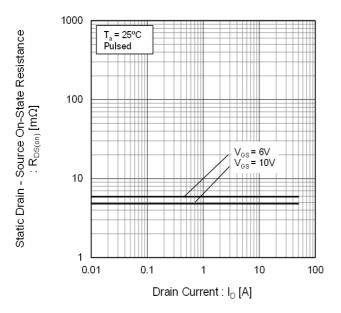


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

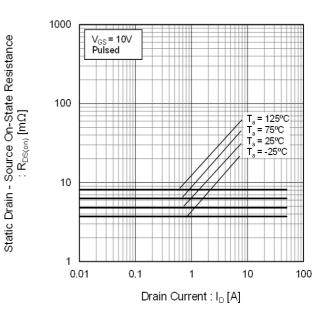
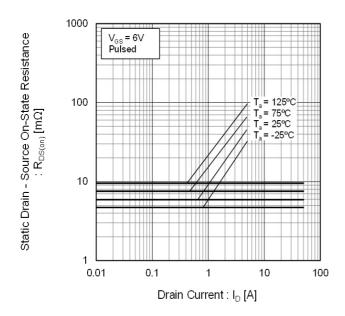


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)



### • Electrical characteristic curves

Fig.17 Typical Capacitance vs.

Drain - Source Voltage

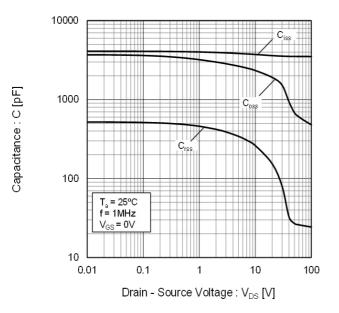


Fig.18 Switching Characteristics

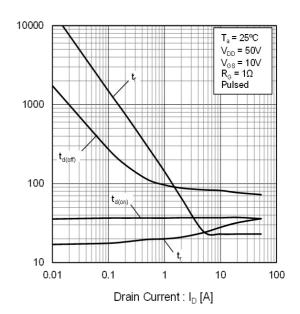
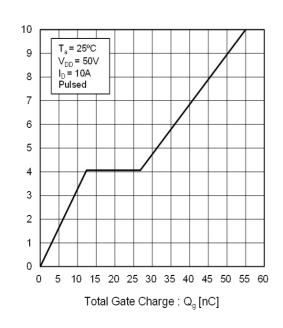


Fig.19 Dynamic Input Characteristics

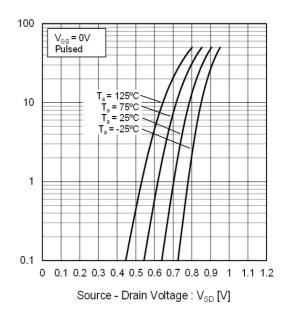


Source Current :  $I_{\rm S}$  [A]

Switching Time: t [ns]

Fig.20 Source Current vs.

Source Drain Voltage



Gate - Source Voltage :  $V_{GS}$  [V]

## Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

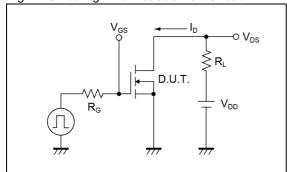


Fig.2-1 Gate Charge Measurement Circuit

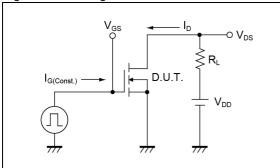


Fig.3-1 Avalanche Measurement Circuit

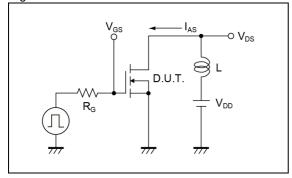


Fig.1-2 Switching Waveforms

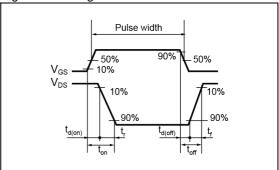


Fig.2-2 Gate Charge Waveform

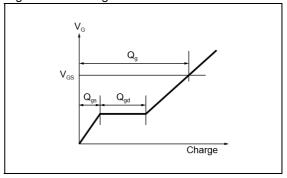
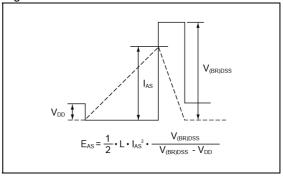
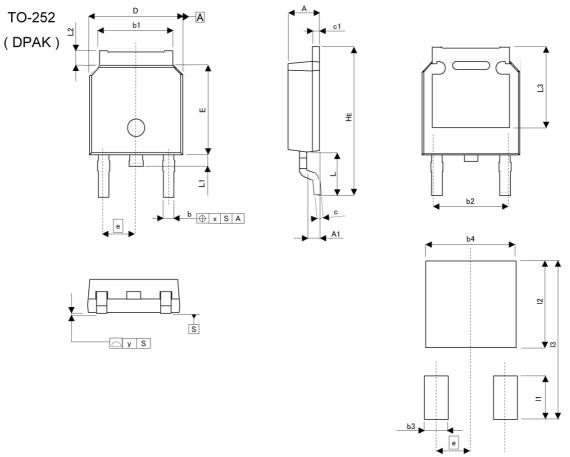


Fig.3-2 Avalanche Waveform



## Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIME	TERS	INCI	HES
DIIVI	MIN	MAX	MIN	MAX
Α	2.10	2.30	0.083	0.091
A1	0.70	1.10	0.028	0.043
b	0.65	0.85	0.026	0.033
b1	5.10	5.40	0.201	0.213
b2	5.	10	0.2	201
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.40	6.80	0.252	0.268
е	2.	30	0.0	91
Е	6.00	6.40	0.236	0.252
HE	9.50	10.50	0.374	0.413
L	2.	90	0.1	14
L1	0.70	0.90	0.028	0.035
L2	0.70	1.30	0.028	0.051
L3	5.	5.30 0.2		209
Х	-	0.25	-	0.010
у	-	0.10	-	0.004

DIM	MILIMETERS		INCHES		
DIIVI	MIN	MAX	MIN	MAX	
b3	o <del>-</del>	1.10	-	0.043	
b4	1-	5.40	-	0.213	
l1	-	2.90	1	0.114	
12	-	5.50	-	0.217	
13	_	10.50	_	0.413	

Dimension in mm/inches



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(Note1) Medical Equipment Classification of the Specific Applications

ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CL ACCIII	CLASS II b	СГУССШ
ſ	CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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